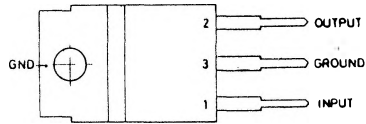




**L78M00
Series**

CONNECTION DIAGRAM AND ORDERING NUMBERS

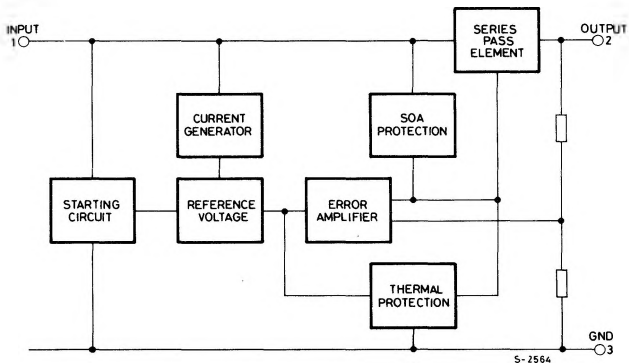
(top view)



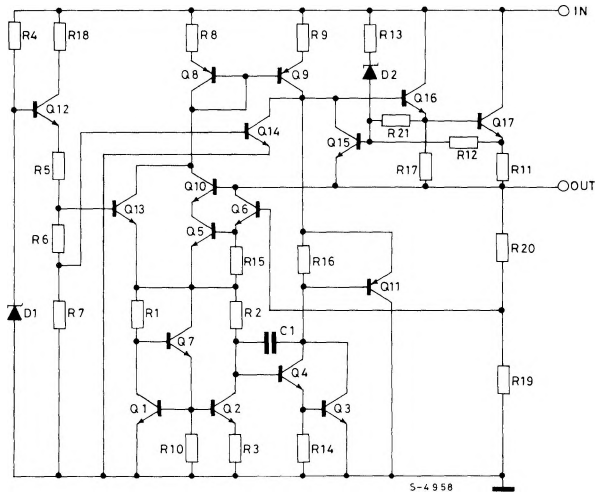
S-2568/1

Ordering Numbers	Output Voltage
L78M05CV	5V
L78M06CV	6V
L78M08CV	8V
L78M12CV	12V
L78M15CV	15V
L78M18CV	18V
L78M20CV	20V
L78M24CV	24V

BLOCK DIAGRAM



SCHEMATIC DIAGRAM



TEST CIRCUITS

Fig. 1 - DC parameters

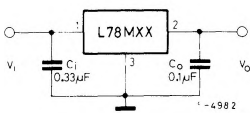


Fig. 2 - Load regulation

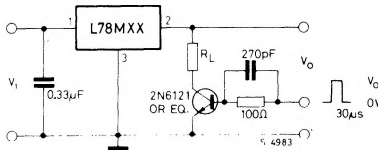
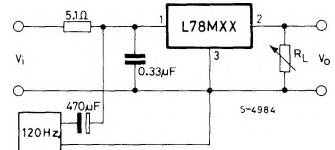


Fig. 3 - Ripple rejection



THERMAL DATA

$R_{th\ j-case}$	Thermal resistance junction-case	max	3	°C/W
$R_{th\ j-amb}$	Thermal resistance junction-ambient	max	50	°C/W



**L78M00
Series**

ELECTRICAL CHARACTERISTICS L78M00C (Refer to the test circuits, $T_j = 25^\circ\text{C}$, $I_o = 350\text{ mA}$ unless otherwise specified, $C_i = 0.33\ \mu\text{F}$, $C_o = 0.1\ \mu\text{F}$)

OUTPUT VOLTAGE		5			6			8			12			Unit
INPUT VOLTAGE (Unless otherwise specified)		10			11			14			19			
Parameter	Test conditions	Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.	
V_o Output voltage		4.8	5	5.2	5.75	6	6.25	7.7	8	8.3	11.5	12	12.5	V
	$I_o = 5$ to 350 mA	4.75	5	5.25 ($V_i = 7$ to 20V)	5.7	6	6.3 ($V_i = 8$ to 21V)	7.6	8	8.4 ($V_i = 10.5$ to 23V)	11.4	12	12.6 ($V_i = 14.5$ to 27V)	
ΔV_o Line regulation	$I_o = 200\text{ mA}$	100 ($V_i = 7$ to 25V)			100 ($V_i = 8$ to 25V)			100 ($V_i = 10.5$ to 25V)			100 ($V_i = 14.5$ to 30V)			mV
		50 ($V_i = 8$ to 25V)			50 ($V_i = 9$ to 25V)			50 ($V_i = 11$ to 25V)			50 ($V_i = 16$ to 30V)			
ΔV_o Load regulation	$I_o = 5\text{ mA}$ to 0.5A	100			120			160			240			mV
	$I_o = 5\text{ mA}$ to 200 mA	50			60			80			120			
I_d Quiescent current		6			6			6			6			mA
ΔI_d Quiescent current change	$I_o = 5\text{ mA}$ to 350 mA	0.5			0.5			0.5			0.5			mA
	$I_o = 200\text{ mA}$	0.8 ($V_i = 8$ to 25V)			0.8 ($V_i = 9$ to 25V)			0.8 ($V_i = 10.5$ to 25V)			0.8 ($V_i = 14.5$ to 30V)			
$\frac{\Delta V_o}{\Delta T}$ Output Voltage drift	$I_o = 5\text{ mA}$ $T_j = 0$ to 125°C	-0.5			-0.5			-0.5			-1.0			mV/ $^\circ\text{C}$
e_N Output noise voltage	$B = 10\text{Hz}$ to 100KHz	40			45			52			75			μV
SVR Supply voltage rejection	$f = 120\text{ Hz}$ $I_o = 300\text{ mA}$	62 ($V_i = 8$ to 18V)			59 ($V_i = 9$ to 19V)			56 ($V_i = 11.5$ to 21.5V)			55 ($V_i = 15$ to 25V)			dB
V_d Dropout voltage		2			2			2			2			V
I_{sc} Short circuit current	$V_i = 35\text{V}$	300			270			250			240			mA
I_{scp} Short circ. peak current		700			700			700			700			mA



**L78M00
Series**

ELECTRICAL CHARACTERISTICS L78M00C (continued)

OUTPUT VOLTAGE		15			18			20			24			Unit
INPUT VOLTAGE (Unless otherwise specified)		23			26			29			33			
Parameter	Test conditions	Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.	
V _o Output Voltage		14.4	15	15.6	17.3	18	18.7	19.2	20	20.8	23	24	25	V
	I _o = 5 to 350 mA	14.25	15	15.75	17.1	18	18.9	19	20	21	22.8	24	25.2	
ΔV _o Line regulation	I _o = 200 mA	100 (V _i = 17.5 to 30V)			100 (V _i = 21 to 33V)			100 (V _i = 23 to 35V)			100 (V _i = 27 to 38V)			mV
		50 (V _i = 20 to 30V)			50 (V _i = 24 to 33V)			50 (V _i = 24 to 35V)			50 (V _i = 28 to 38V)			
ΔV _o Load regulation	I _o = 5 mA to 0.5A	300			360			400			480			mV
	I _o = 5 mA to 200 mA	150			180			200			240			
I _d Quiescent current		6			6			6			6			mA
ΔI _d Quiescent current change	I _o = 5 mA to 350 mA	0.5			0.5			0.5			0.5			mA
	I _o = 200 mA	0.8 (V _i = 17.5 to 30V)			0.8 (V _i = 21 to 33V)			0.8 (V _i = 23 to 35V)			0.8 (V _i = 27 to 38V)			
ΔV _o / ΔT Output voltage drift	I _o = 5 mA T _{amb} = 0 to 125°C	-1			-1.1			-1.1			-1.2			mV/°C
e _N Output noise voltage	B = 10Hz to 100KHz	90			100			110			170			μV
SVR Supply voltage rejection	f = 120 Hz I _o = 300 mA	54 (V _i = 18.5 to 28.5V)			53 (V _i = 22 to 32V)			53 (V _i = 24 to 34V)			50 (V _i = 28 to 38V)			dB
V _d Dropout Voltage		2			2			2			2			V
I _{sc} Short circuit current	V _i = 35V	240			240			240			240			mA
I _{scp} Short circ. peak current		700			700			700			700			mA



L78M00 Series

Fig. 4 - Dropout voltage vs. junction temperature

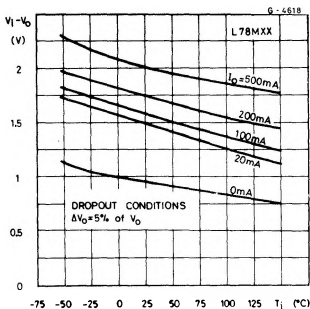


Fig. 5 - Dropout characteristics

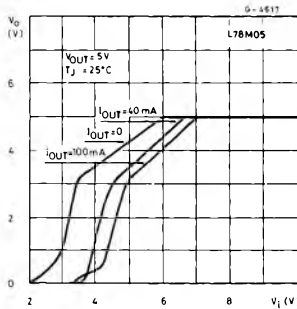


Fig. 6 - Peak output current vs. input-output differential voltage

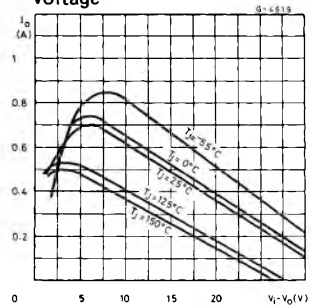


Fig. 7 - Output voltage vs. junction temperature

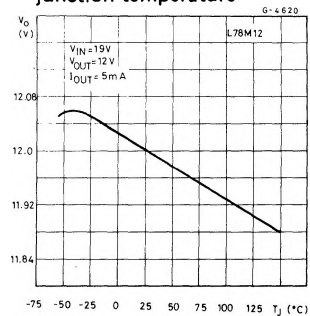


Fig. 8 - Supply voltage rejection vs. frequency

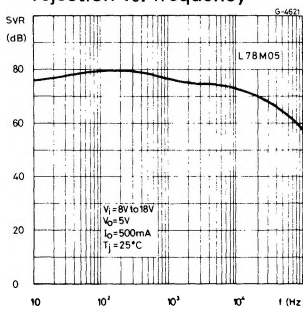


Fig. 9 - Quiescent current vs. junction temperature

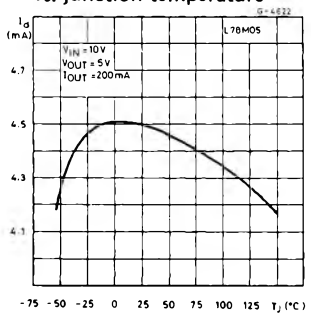


Fig. 10 - Load transient response

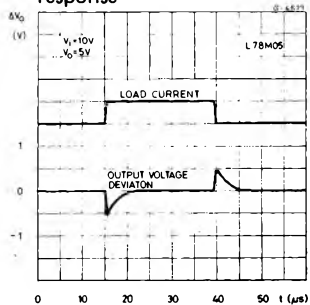


Fig. 11 - Line transient response

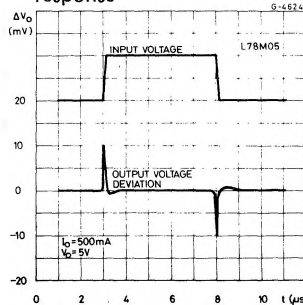
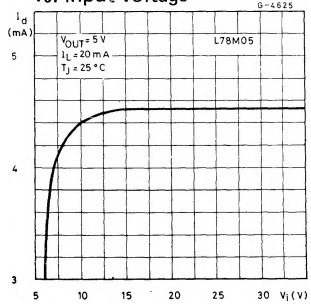
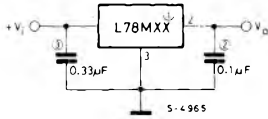


Fig. 12 - Quiescent current vs. input voltage



APPLICATION INFORMATION (continued)

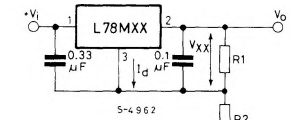
Fig. 13 - Fixed output regulator



Notes:

- (1) To specify an output voltage, substitute voltage value for "XX".
- (2) Although no output capacitor is needed for stability, it does improve transient response.
- (3) Required if regulator is located an appreciable distance from power supply filter.

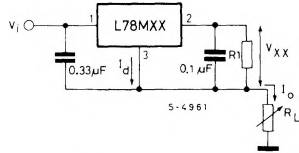
Fig. 15 - Circuit for increasing output voltage



$$I_{R1} \geq 5 I_d$$

$$V_o = V_{XX} \left(1 + \frac{R_2}{R_1} \right) + I_d R_2$$

Fig. 14 - Constant current regulator



$$I_o = \frac{V_{XX}}{R_1} + I_d$$

Fig. 16 - Adjustable output regulator (7 to 30V)

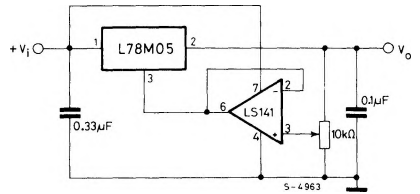
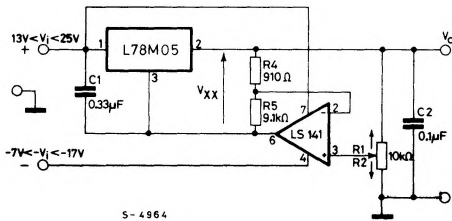
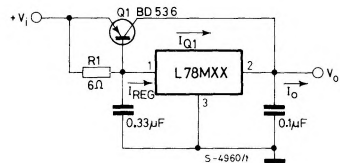


Fig. 17 - 0.5 to 10V regulator



$$V_o = V_{XX} \frac{R_4}{R_1}$$

Fig. 18 - High current voltage regulator



$$R_1 = \frac{V_{BEQ1}}{I_{REG} - \frac{I_{Q1}}{\beta_{Q1}}}$$

$$I_o = I_{REG} + \beta_{Q1} \left[I_{REG} - \frac{V_{BEQ1}}{R_1} \right]$$

APPLICATION INFORMATION (continued)

Fig. 19 - High output current with short circuit protection

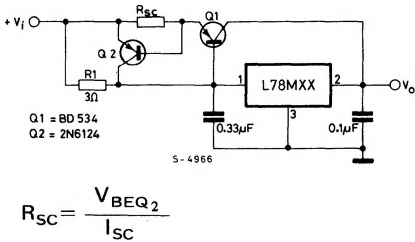
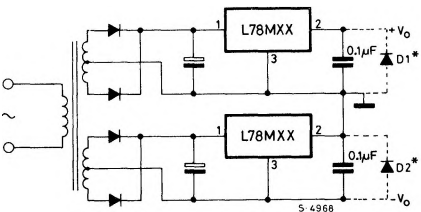
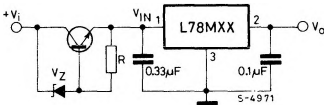


Fig. 21 - Positive and negative regulator



(*)D₁ and D₂ are necessary if the load is connected between +V_O and -V_O

Fig. 23 - High input voltage circuit



$$V_{IN} = V_i - (V_Z + V_{BE})$$

Fig. 20 - Tracking voltage regulator

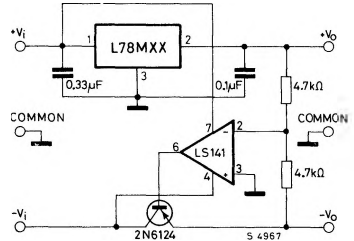


Fig. 22 - Negative output voltage circuit

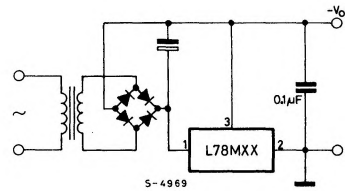
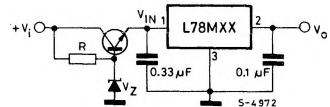


Fig. 24 - High input voltage circuit



$$V_{IN} = V_Z - V_{BE}$$

APPLICATION INFORMATION (continued)

Fig. 25 - High output voltage regulator

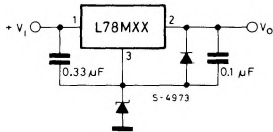
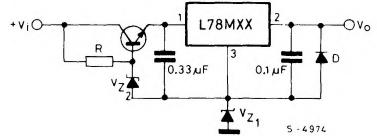
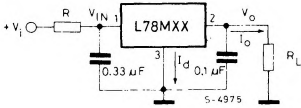


Fig. 26 - High input and output voltage



$$V_o = V_{XX} + V_{Z1}$$

Fig. 27 - Reducing power dissipation with dropping resistor



$$R = \frac{V_{i(\min)} - V_{XX} - V_{DROPP(\max)}}{I_o(\max) + I_d(\max)}$$

Fig. 28 - Remote shutdown

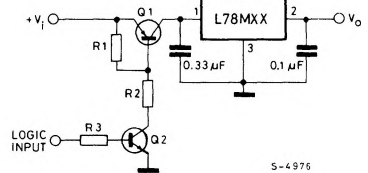


Fig. 29 - Power AM modulator (unity voltage gain, $I_o \leq 0.5$)

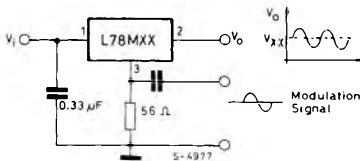
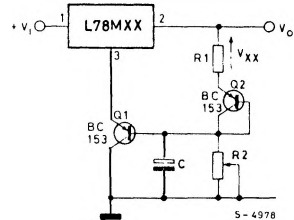


Fig. 30 - Adjustable output voltage with temperature compensation



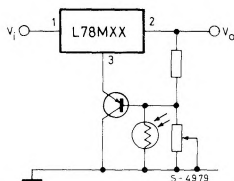
Note: Q_2 is connected as a diode in order to compensate the variation of the Q_1 V_{BE} with the temperature. C allows a slow rise-time of the V_o

$$V_o = V_{XX} \left(1 + \frac{R_2}{R_1} \right) + V_{BE}$$

Note: The circuit performs well up to 100 KHz.

APPLICATION INFORMATION (continued)
Fig. 31 - Light controllers ($V_o \text{ min} = V_{XX} + V_{BE}$)

(a)


 V_o falls when the light goes up

(b)

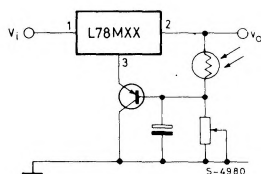
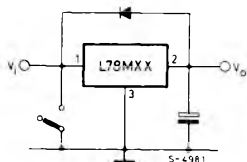

 V_o rises when the light goes up

Fig. 32 - Protection against input short-circuit with high capacitance loads


Applications with high capacitance loads and an output voltage greater than 6 volts need an external diode (see fig. 32) to protect the device against input short circuit. In this case the input voltage falls rapidly while the output voltage decreases slowly. The capacitance discharges by means of the Base-Emitter junction of the series pass transistor in the regulator. If the energy is sufficiently high, the transistor may be destroyed. The external diode by-passes the current from the IC to ground.